

Abstract of the Disclosure

It is provided an organic semiconductor element having an FET which can control a channel length to a small value and does not cause a rise in contact resistance due to a step portion, 5 and an organic light emitting display device with a large aperture using the same. A first conductive layer (2) which is one of source/drain electrodes is provided onto a substrate (1), and an organic semiconductor layer (3) and a second conductive layer (4) which is the other electrode of the source/drain electrodes 10 are provided onto the first conductive layer (2). Then on a side face of the organic semiconductor layer or a front surface of the organic semiconductor layer (3) exposed by removing a part of the second conductive layer and a side face of the second conductive layer a gate electrode (third conductive layer) (6) 15 is provided via an insulating layer (5), thereby to form an FET. The organic EL display device has the FET having such structure laminated on an organic EL section as a drive element.